

# 74HC1G125-Q100; 74HCT1G125-Q100

Bus buffer/line driver; 3-state

Rev. 1 — 18 June 2013

Product data sheet

## 1. General description

The 74HC1G125-Q100; 74HCT1G125-Q100 is a single buffer/line driver with 3-state output. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from  $-40\text{ °C}$  to  $+85\text{ °C}$  and from  $-40\text{ °C}$  to  $+125\text{ °C}$
- Input levels:
  - ◆ For 74HC1G125-Q100: CMOS level
  - ◆ For 74HCT1G125-Q100: TTL level
- Symmetrical output impedance
- High noise immunity
- Low power consumption
- Balanced propagation delays
- ESD protection:
  - ◆ MIL-STD-883, method 3015 exceeds 2000 V
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V ( $C = 200\text{ pF}$ ,  $R = 0\ \Omega$ )

## 3. Ordering information

Table 1. Ordering information

| Type number       | Package                             |        |  |          |
|-------------------|-------------------------------------|--------|--|----------|
|                   | Temperature range                   | Name   | Description  | Version  |
| 74HC1G125GW-Q100  | $-40\text{ °C}$ to $+125\text{ °C}$ | TSSOP5 | plastic thin shrink small outline package; 5 leads; body width 1.25 mm | SOT353-1 |
| 74HCT1G125GW-Q100 |                                     |        |  |          |
| 74HC1G125GV-Q100  | $-40\text{ °C}$ to $+125\text{ °C}$ | SC-74A | plastic surface mounted package; 5 leads                               | SOT753   |
| 74HCT1G125GV-Q100 |                                     |        |  |          |

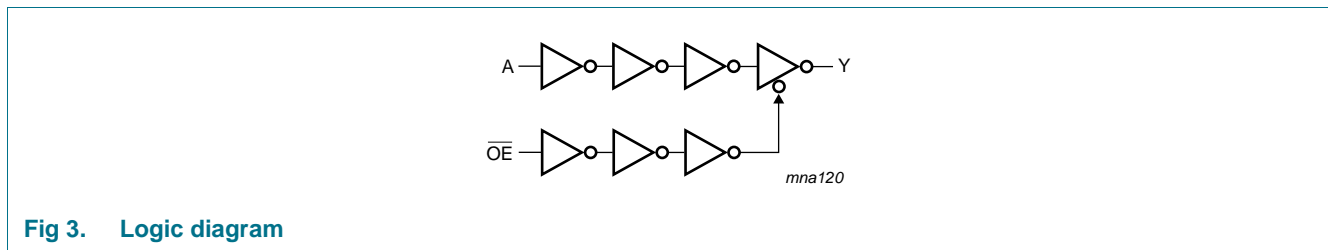
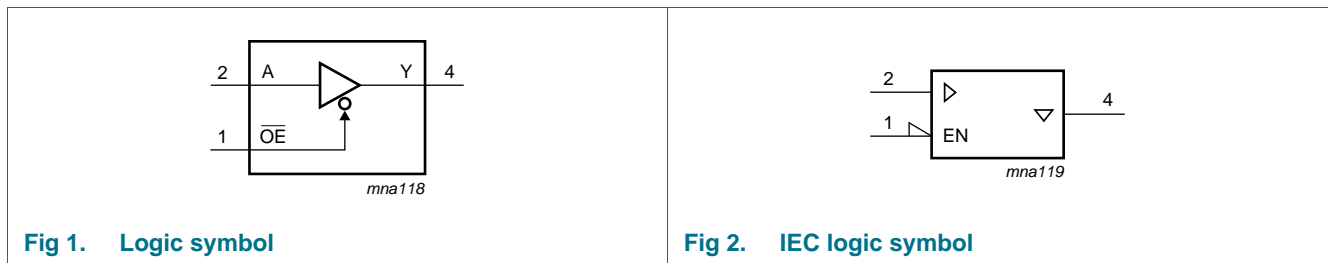
## 4. Marking

Table 2. Marking

| Type number       | Marking code <sup>[1]</sup> |
|-------------------|-----------------------------|
| 74HC1G125GW-Q100  | HM                          |
| 74HCT1G125GW-Q100 | TM                          |
| 74HC1G125GV-Q100  | H25                         |
| 74HCT1G125GV-Q100 | T25                         |

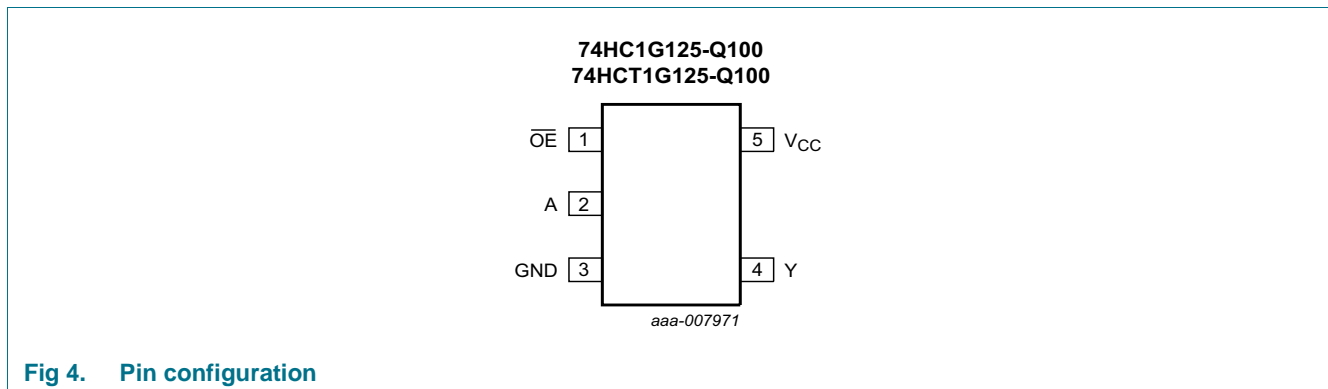
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram



## 6. Pinning information

### 6.1 Pinning



## 6.2 Pin description

Table 3. Pin description

| Symbol          | Pin | Description                      |
|-----------------|-----|----------------------------------|
| $\overline{OE}$ | 1   | output enable input (active LOW) |
| A               | 2   | data input                       |
| GND             | 3   | ground (0 V)                     |
| Y               | 4   | data output                      |
| $V_{CC}$        | 5   | supply voltage                   |

## 7. Functional description

### 7.1 Function table

Table 4. Function table<sup>[1]</sup>

| Control         | Input | Output |
|-----------------|-------|--------|
| $\overline{OE}$ | A     | Y      |
| L               | L     | L      |
| L               | H     | H      |
| H               | X     | Z      |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions   | Min   | Max      | Unit |
|-----------|-------------------------|--|-------|----------|------|
| $V_{CC}$  | supply voltage          |  | -0.5  | +7.0     | V    |
| $I_{IK}$  | input clamping current  | $V_I < -0.5 \text{ V}$ or $V_I > V_{CC} + 0.5 \text{ V}$ | [1] - | $\pm 20$ | mA   |
| $I_{OK}$  | output clamping current | $V_O < -0.5 \text{ V}$ or $V_O > V_{CC} + 0.5 \text{ V}$ | [1] - | $\pm 20$ | mA   |
| $I_O$     | output current          | $V_O = -0.5 \text{ V}$ to $(V_{CC} + 0.5 \text{ V})$     | [1] - | $\pm 35$ | mA   |
| $I_{CC}$  | supply current          |  | -     | 70       | mA   |
| $I_{GND}$ | ground current          |  | -70   | -        | mA   |
| $T_{stg}$ | storage temperature     |  | -65   | +150     | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40 \text{ °C}$ to $+125 \text{ °C}$          | [2] - | 200      | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] Above 55 °C the value of  $P_{tot}$  derates linearly with 2.5 mW/K.

## 9. Recommended operating conditions

**Table 6. Recommended operating conditions**

Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                           | Conditions              | 74HC1G125-Q100 |     |                 | 74HCT1G125-Q100 |     |                 | Unit |
|------------------|-------------------------------------|-------------------------|----------------|-----|-----------------|-----------------|-----|-----------------|------|
|                  |                                     |                         | Min            | Typ | Max             | Min             | Typ | Max             |      |
| V <sub>CC</sub>  | supply voltage                      |                         | 2.0            | 5.0 | 6.0             | 4.5             | 5.0 | 5.5             | V    |
| V <sub>I</sub>   | input voltage                       |                         | 0              | -   | V <sub>CC</sub> | 0               | -   | V <sub>CC</sub> | V    |
| V <sub>O</sub>   | output voltage                      |                         | 0              | -   | V <sub>CC</sub> | 0               | -   | V <sub>CC</sub> | V    |
| T <sub>amb</sub> | ambient temperature                 |                         | -40            | +25 | +125            | -40             | +25 | +125            | °C   |
| Δt/ΔV            | input transition rise and fall rate | V <sub>CC</sub> = 2.0 V | -              | -   | 625             | -               | -   | -               | ns/V |
|                  |                                     | V <sub>CC</sub> = 4.5 V | -              | -   | 139             | -               | -   | 139             | ns/V |
|                  |                                     | V <sub>CC</sub> = 6.0 V | -              | -   | 83              | -               | -   | -               | ns/V |

## 10. Static characteristics

**Table 7. Static characteristics 74HC1G125-Q100**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol  | Parameter                 | Conditions   | Min  | Typ  | Max  | Unit |
|---|---------------------------|--|------|------|------|------|
| <b>T<sub>amb</sub> = -40 °C to +85 °C [1]</b> |                           |  |      |      |      |      |
| V <sub>IH</sub>                               | HIGH-level input voltage  | V <sub>CC</sub> = 2.0 V  | 1.5  | 1.2  | -    | V    |
|   |                           | V <sub>CC</sub> = 4.5 V  | 3.15 | 2.4  | -    | V    |
|   |                           | V <sub>CC</sub> = 6.0 V  | 4.2  | 3.2  | -    | V    |
| V <sub>IL</sub>                               | LOW-level input voltage   | V <sub>CC</sub> = 2.0 V  | -    | 0.8  | 0.5  | V    |
|   |                           | V <sub>CC</sub> = 4.5 V  | -    | 2.1  | 1.35 | V    |
|   |                           | V <sub>CC</sub> = 6.0 V  | -    | 2.8  | 1.8  | V    |
| V <sub>OH</sub>                               | HIGH-level output voltage | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |      |      |      |      |
|   |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V   | 1.9  | 2.0  | -    | V    |
|   |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V   | 4.4  | 4.5  | -    | V    |
|   |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V   | 5.9  | 6.0  | -    | V    |
|   |                           | I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V  | 3.84 | 4.32 | -    | V    |
| V <sub>OL</sub>                               | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |      |      |      |      |
|   |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V  | -    | 0    | 0.1  | V    |
|   |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V  | -    | 0    | 0.1  | V    |
|   |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V  | -    | 0    | 0.1  | V    |
|   |                           | I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V   | -    | 0.15 | 0.33 | V    |
| I <sub>I</sub>                                | input leakage current     | I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V   | -    | 0.16 | 0.33 | V    |
|   |                           | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V   | -    | -    | 1.0  | μA   |
| I <sub>OZ</sub>                               | OFF-state output current  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V | -    | -    | 5    | μA   |
| I <sub>CC</sub>                               | supply current            | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V                                 | -    | -    | 10   | μA   |
| C <sub>I</sub>                                | input capacitance         |  | -    | 1.5  | -    | pF   |

**Table 7.** Static characteristics 74HC1G125-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                 | Conditions   | Min  | Typ | Max  | Unit |
|--|---------------------------|--|------|-----|------|------|
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                           |  |      |     |      |      |
| V <sub>IH</sub>                            | HIGH-level input voltage  | V <sub>CC</sub> = 2.0 V  | 1.5  | -   | -    | V    |
|  |                           | V <sub>CC</sub> = 4.5 V  | 3.15 | -   | -    | V    |
|  |                           | V <sub>CC</sub> = 6.0 V  | 4.2  | -   | -    | V    |
| V <sub>IL</sub>                            | LOW-level input voltage   | V <sub>CC</sub> = 2.0 V  | -    | -   | 0.5  | V    |
|  |                           | V <sub>CC</sub> = 4.5 V  | -    | -   | 1.35 | V    |
|  |                           | V <sub>CC</sub> = 6.0 V  | -    | -   | 1.8  | V    |
| V <sub>OH</sub>                            | HIGH-level output voltage | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |      |     |      |      |
|  |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V   | 1.9  | -   | -    | V    |
|  |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V   | 4.4  | -   | -    | V    |
|  |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V   | 5.9  | -   | -    | V    |
|  |                           | I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V  | 3.7  | -   | -    | V    |
| V <sub>OL</sub>                            | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |      |     |      |      |
|  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V  | -    | -   | 0.1  | V    |
|  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V  | -    | -   | 0.1  | V    |
|  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V  | -    | -   | 0.1  | V    |
|  |                           | I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V   | -    | -   | 0.4  | V    |
|  |                           | I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V   | -    | -   | 0.4  | V    |
|  |                           |  |      |     |      |      |
| I <sub>I</sub>                             | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V   | -    | -   | 1.0  | μA   |
| I <sub>OZ</sub>                            | OFF-state output current  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V | -    | -   | 10   | μA   |
| I <sub>CC</sub>                            | supply current            | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V                                 | -    | -   | 20   | μA   |

[1] All typical values are measured at T<sub>amb</sub> = 25 °C.

**Table 8. Static characteristics 74HCT1G125-Q100**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol  | Parameter                 | Conditions   | Min  | Typ  | Max  | Unit          |
|---|---------------------------|--|------|------|------|---------------|
| <b><math>T_{amb} = -40\text{ °C to }+85\text{ °C}</math>[1]</b> |                           |  |      |      |      |               |
| $V_{IH}$  | HIGH-level input voltage  | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$  | 2.0  | 1.6  | -    | V             |
| $V_{IL}$  | LOW-level input voltage   | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$  | -    | 1.2  | 0.8  | V             |
| $V_{OH}$  | HIGH-level output voltage | $V_I = V_{IH}\text{ or }V_{IL}; V_{CC} = 4.5\text{ V}$                                 |      |      |      |               |
|   |                           | $I_O = -20\text{ }\mu\text{A}$   | 4.4  | 4.5  | -    | V             |
|   |                           | $I_O = -6.0\text{ mA}$   | 3.84 | 4.32 | -    | V             |
| $V_{OL}$  | LOW-level output voltage  | $V_I = V_{IH}\text{ or }V_{IL}; V_{CC} = 4.5\text{ V}$                                 |      |      |      |               |
|   |                           | $I_O = 20\text{ }\mu\text{A}$  | -    | 0    | 0.1  | V             |
|   |                           | $I_O = 6.0\text{ mA}$  | -    | 0.16 | 0.33 | V             |
| $I_I$   | input leakage current     | $V_I = V_{CC}\text{ or GND}; V_{CC} = 5.5\text{ V}$                                    | -    | -    | 1.0  | $\mu\text{A}$ |
| $I_{OZ}$  | OFF-state output current  | $V_I = V_{IH}\text{ or }V_{IL}; V_O = V_{CC}\text{ or GND}; V_{CC} = 5.5\text{ V}$     | -    | -    | 5    | $\mu\text{A}$ |
| $I_{CC}$  | supply current            | $V_I = V_{CC}\text{ or GND}; I_O = 0\text{ A}; V_{CC} = 5.5\text{ V}$                  | -    | -    | 10   | $\mu\text{A}$ |
| $\Delta I_{CC}$   | additional supply current | $V_I = V_{CC} - 2.1\text{ V}; I_O = 0\text{ A}; V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | -    | -    | 500  | $\mu\text{A}$ |
| $C_I$   | input capacitance         |  | -    | 1.5  | -    | pF            |
| <b><math>T_{amb} = -40\text{ °C to }+125\text{ °C}</math></b>   |                           |  |      |      |      |               |
| $V_{IH}$  | HIGH-level input voltage  | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$  | 2.0  | -    | -    | V             |
| $V_{IL}$  | LOW-level input voltage   | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$  | -    | -    | 0.8  | V             |
| $V_{OH}$  | HIGH-level output voltage | $V_I = V_{IH}\text{ or }V_{IL}; V_{CC} = 4.5\text{ V}$                                 |      |      |      |               |
|   |                           | $I_O = -20\text{ }\mu\text{A}$   | 4.4  | -    | -    | V             |
|   |                           | $I_O = -6.0\text{ mA}$   | 3.7  | -    | -    | V             |
| $V_{OL}$  | LOW-level output voltage  | $V_I = V_{IH}\text{ or }V_{IL}; V_{CC} = 4.5\text{ V}$                                 |      |      |      |               |
|   |                           | $I_O = 20\text{ }\mu\text{A}$  | -    | -    | 0.1  | V             |
|   |                           | $I_O = 6.0\text{ mA}$  | -    | -    | 0.4  | V             |
| $I_I$   | input leakage current     | $V_I = V_{CC}\text{ or GND}; V_{CC} = 5.5\text{ V}$                                    | -    | -    | 1.0  | $\mu\text{A}$ |
| $I_{OZ}$  | OFF-state output current  | $V_I = V_{IH}\text{ or }V_{IL}; V_O = V_{CC}\text{ or GND}; V_{CC} = 5.5\text{ V}$     | -    | -    | 10   | $\mu\text{A}$ |
| $I_{CC}$  | supply current            | $V_I = V_{CC}\text{ or GND}; I_O = 0\text{ A}; V_{CC} = 5.5\text{ V}$                  | -    | -    | 20   | $\mu\text{A}$ |
| $\Delta I_{CC}$   | additional supply current | $V_I = V_{CC} - 2.1\text{ V}; I_O = 0\text{ A}; V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | -    | -    | 850  | $\mu\text{A}$ |

[1] All typical values are measured at  $T_{amb} = 25\text{ °C}$ .

## 11. Dynamic characteristics

**Table 9. Dynamic characteristics 74HC1G125-Q100**

 Voltages are referenced to GND (ground = 0 V); CL = 50 pF unless otherwise specified; for test circuit see [Figure 7](#)

| Symbol  | Parameter                     | Conditions  | Min | Typ | Max | Unit |
|---|-------------------------------|---|-----|-----|-----|------|
| <b>T<sub>amb</sub> = -40 °C to +85 °C</b> [1] |                               |   |     |     |     |      |
| t <sub>pd</sub>                               | propagation delay             | A to Y; see <a href="#">Figure 5</a>                      | [2] |     |     |      |
|   |                               | V <sub>CC</sub> = 2.0 V                                   | -   | 24  | 125 | ns   |
|   |                               | V <sub>CC</sub> = 4.5 V                                   | -   | 10  | 25  | ns   |
|   |                               | V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF             | -   | 9   | -   | ns   |
|   |                               | V <sub>CC</sub> = 6.0 V                                   | -   | 8   | 21  | ns   |
| t <sub>en</sub>                               | enable time                   | $\overline{\text{OE}}$ to Y; see <a href="#">Figure 6</a> | [2] |     |     |      |
|   |                               | V <sub>CC</sub> = 2.0 V                                   | -   | 19  | 155 | ns   |
|   |                               | V <sub>CC</sub> = 4.5 V                                   | -   | 9   | 31  | ns   |
|   |                               | V <sub>CC</sub> = 6.0 V                                   | -   | 7   | 26  | ns   |
| t <sub>dis</sub>                              | disable time                  | $\overline{\text{OE}}$ to Y; see <a href="#">Figure 6</a> | [2] |     |     |      |
|   |                               | V <sub>CC</sub> = 2.0 V                                   | -   | 18  | 155 | ns   |
|   |                               | V <sub>CC</sub> = 4.5 V                                   | -   | 12  | 31  | ns   |
|   |                               | V <sub>CC</sub> = 6.0 V                                   | -   | 11  | 26  | ns   |
| C <sub>PD</sub>                               | power dissipation capacitance | V <sub>I</sub> = GND to V <sub>CC</sub>                   | [3] | -   | 30  | pF   |
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b>    |                               |   |     |     |     |      |
| t <sub>pd</sub>                               | propagation delay             | A to Y; see <a href="#">Figure 5</a>                      | [2] |     |     |      |
|   |                               | V <sub>CC</sub> = 2.0 V                                   | -   | -   | 150 | ns   |
|   |                               | V <sub>CC</sub> = 4.5 V                                   | -   | -   | 30  | ns   |
|   |                               | V <sub>CC</sub> = 6.0 V                                   | -   | -   | 26  | ns   |
| t <sub>en</sub>                               | enable time                   | $\overline{\text{OE}}$ to Y; see <a href="#">Figure 6</a> | [2] |     |     |      |
|   |                               | V <sub>CC</sub> = 2.0 V                                   | -   | -   | 190 | ns   |
|   |                               | V <sub>CC</sub> = 4.5 V                                   | -   | -   | 38  | ns   |
|   |                               | V <sub>CC</sub> = 6.0 V                                   | -   | -   | 32  | ns   |
| t <sub>dis</sub>                              | disable time                  | $\overline{\text{OE}}$ to Y; see <a href="#">Figure 6</a> | [2] |     |     |      |
|   |                               | V <sub>CC</sub> = 2.0 V                                   | -   | -   | 190 | ns   |
|   |                               | V <sub>CC</sub> = 4.5 V                                   | -   | -   | 38  | ns   |
|   |                               | V <sub>CC</sub> = 6.0 V                                   | -   | -   | 32  | ns   |

[1] All typical values are measured at T<sub>amb</sub> = 25 °C.

[2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.

t<sub>en</sub> is the same as t<sub>PZL</sub> and t<sub>PZH</sub>.

t<sub>dis</sub> is the same as t<sub>PLZ</sub> and t<sub>PHZ</sub>.

[3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

**Table 10. Dynamic characteristics 74HCT1G125-Q100**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit see [Figure 7](#)

| Symbol   | Parameter                     | Conditions  | Min | Typ <sup>[1]</sup> | Max | Unit |    |
|--|-------------------------------|---|-----|--------------------|-----|------|----|
| <b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b>  |                               |   |     |                    |     |      |    |
| $t_{pd}$   | propagation delay             | A to Y; see <a href="#">Figure 5</a>                                    | [2] |                    |     |      |    |
|  |                               | $V_{CC} = 4.5$ V  | -   | 11                 | 30  | ns   |    |
|  |                               | $V_{CC} = 5$ V; $C_L = 15$ pF   | -   | 10                 | -   | ns   |    |
| $t_{en}$   | enable time                   | $V_{CC} = 4.5$ V; $\overline{OE}$ to Y;<br>see <a href="#">Figure 6</a> | [2] | -                  | 10  | 35   | ns |
| $t_{dis}$  | disable time                  | $V_{CC} = 4.5$ V; $\overline{OE}$ to Y;<br>see <a href="#">Figure 6</a> | [2] | -                  | 11  | 31   | ns |
| $C_{PD}$   | power dissipation capacitance | $V_I = GND$ to $V_{CC} - 1.5$ V   | [3] | -                  | 27  | -    | pF |
| <b><math>T_{amb} = -40</math> °C to <math>+125</math> °C</b> |                               |   |     |                    |     |      |    |
| $t_{pd}$   | propagation delay             | $V_{CC} = 4.5$ V; A to Y; see <a href="#">Figure 5</a>                  | [2] | -                  | -   | 36   | ns |
| $t_{en}$   | enable time                   | $V_{CC} = 4.5$ V; $\overline{OE}$ to Y;<br>see <a href="#">Figure 6</a> | [2] | -                  | -   | 42   | ns |
| $t_{dis}$  | disable time                  | $V_{CC} = 4.5$ V; $\overline{OE}$ to Y;<br>see <a href="#">Figure 6</a> | [2] | -                  | -   | 38   | ns |

[1] All typical values are measured at  $T_{amb} = 25$  °C.

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

$t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ .

$t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

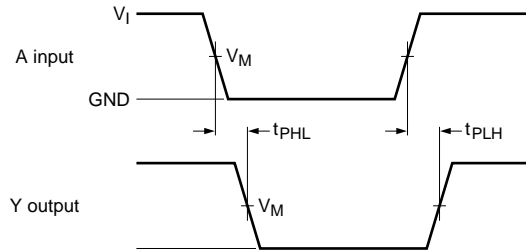
$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.



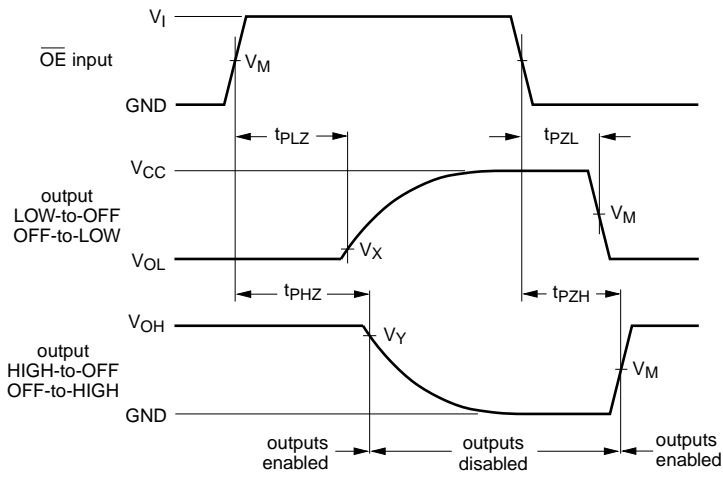
12. Waveforms



001aad070

Measurement points are given in [Table 11](#).

Fig 5. Propagation delay data input (A) to output (Y)



mna644

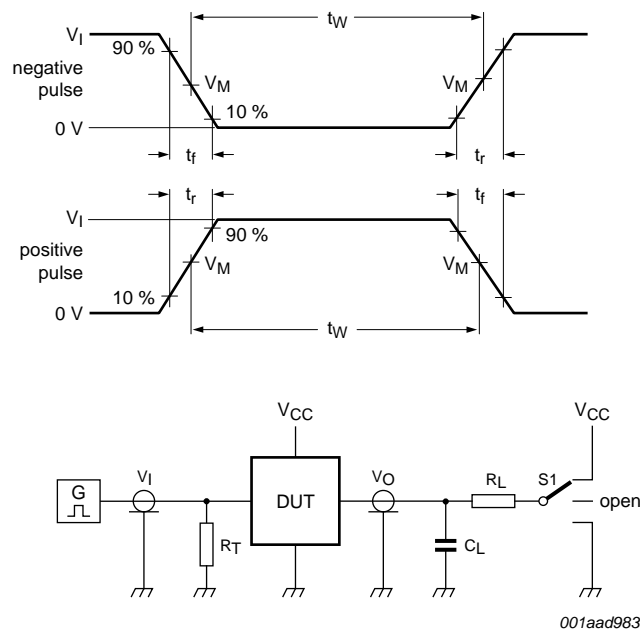
Measurement points are given in [Table 11](#).

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage drop that occur with the output load.

Fig 6. Enable and disable times

Table 11. Measurement points

| Type            | Input       | Output      |                  |                  |
|-----------------|-------------|-------------|------------------|------------------|
|                 | $V_M$       | $V_M$       | $V_X$            | $V_Y$            |
| 74HC1G125-Q100  | $0.5V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.3 V$ | $V_{OH} - 0.3 V$ |
| 74HCT1G125-Q100 | 1.3 V       | 1.3 V       | $V_{OL} + 0.3 V$ | $V_{OH} - 0.3 V$ |



Test data is given in [Table 12](#).

Definitions for test circuit:

$R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator

$C_L$  = Load capacitance including jig and probe capacitance

$R_L$  = Load resistor

S1 = Test selection switch

**Fig 7. Test circuit for measuring switching times**

**Table 12. Test data**

| Type            | Input    |            | Load         |              | S1 position        |                    |                    |
|-----------------|----------|------------|--------------|--------------|--------------------|--------------------|--------------------|
|                 | $V_I$    | $t_r, t_f$ | $C_L$        | $R_L$        | $t_{PLH}, t_{PHL}$ | $t_{PZH}, t_{PHZ}$ | $t_{PZL}, t_{PLZ}$ |
| 74HC1G125-Q100  | $V_{CC}$ | 6 ns       | 15 pF, 50 pF | 1 k $\Omega$ | open               | GND                | $V_{CC}$           |
| 74HCT1G125-Q100 | 3 V      | 6 ns       | 15 pF, 50 pF | 1 k $\Omega$ | open               | GND                | $V_{CC}$           |

## 13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1

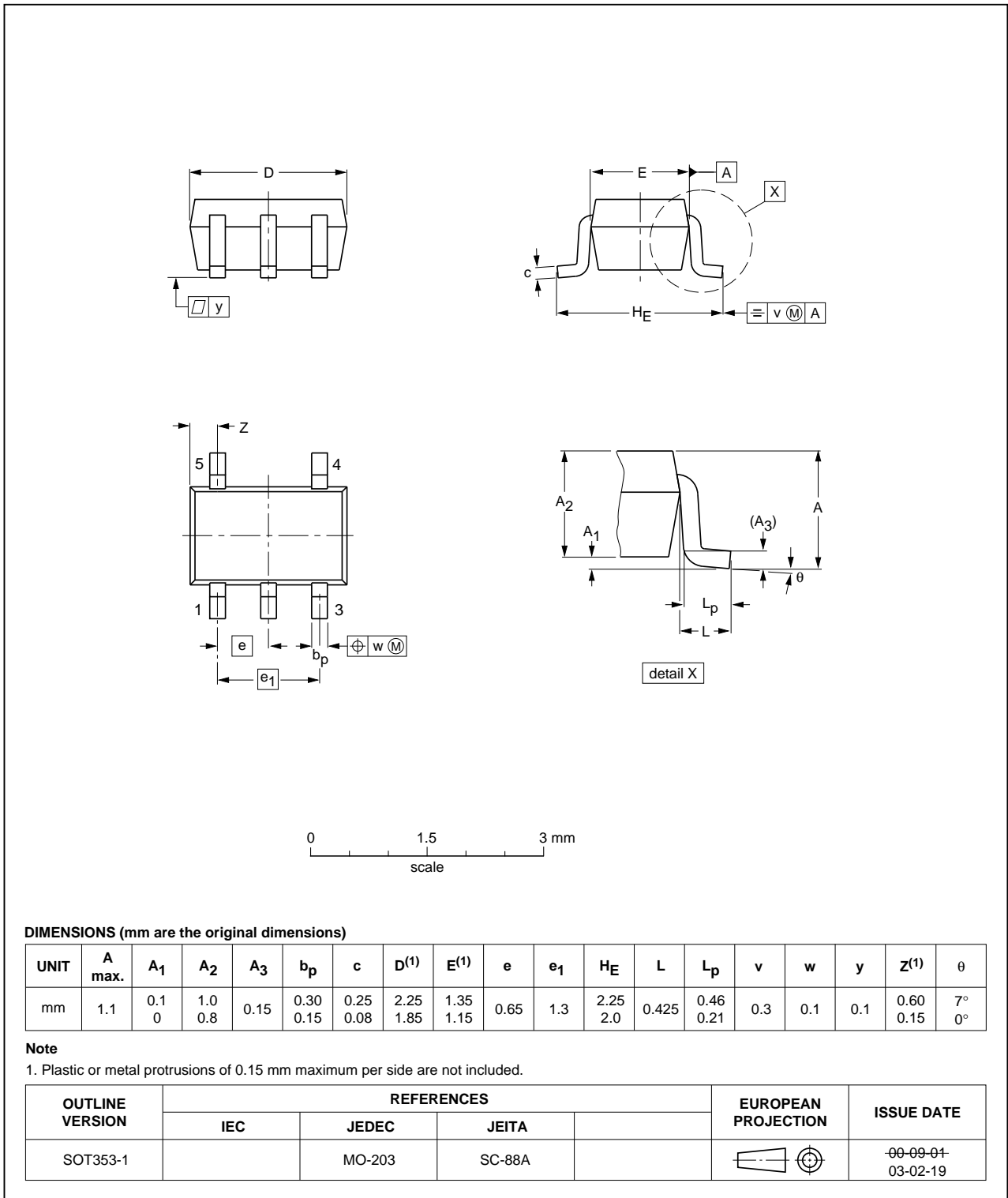


Fig 8. Package outline SOT353-1 (TSSOP5)

Plastic surface-mounted package; 5 leads

SOT753

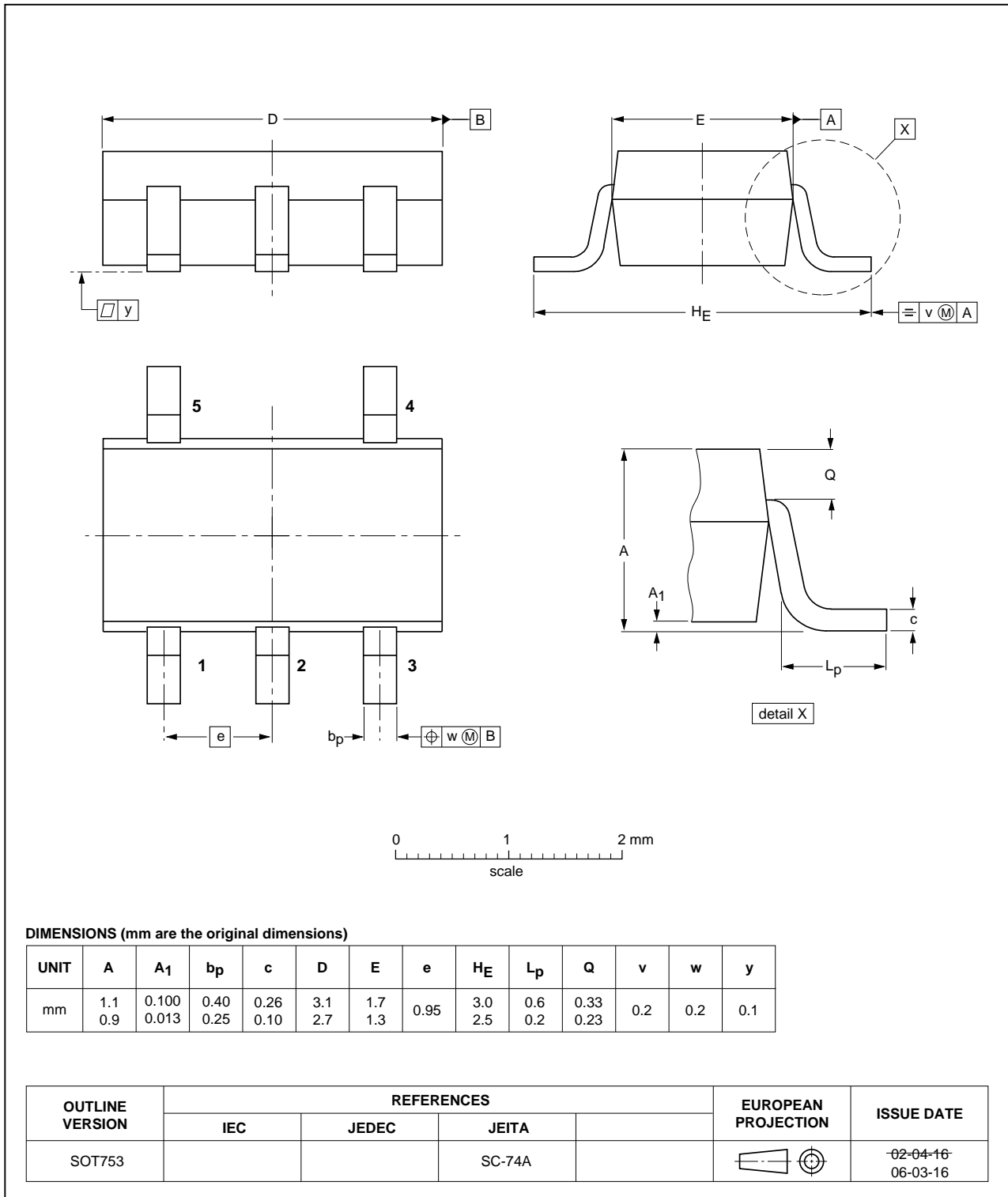


Fig 9. Package outline SOT753 (SC-74A)

## 14. Abbreviations

**Table 13. Abbreviations**

| Acronym | Description                             |
|---------|---|
| CMOS    | Complementary Metal Oxide Semiconductor |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| TTL     | Transistor-Transistor Logic             |
| MM      | Machine Model                           |

## 15. Revision history

**Table 14. Revision history**

| Document ID            | Release date | Data sheet status  | Change notice | Supersedes |
|------------------------|--------------|--------------------|---------------|------------|
| 74HC_HCT1G125_Q100 v.1 | 20130618     | Product data sheet | -             | -          |

## 16. Legal information

### 16.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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